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## FAST-SWITCHING POWER TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE
- NPN TRANSISTOR
- $\mathrm{h}_{\text {FE }}>10$ AT $\mathrm{I}_{\mathrm{C}}=35 \mathrm{~A}$
- HIGH EFFICIENCY SWITCHING
- VERY LOW SATURATION VOLTAGE
- RECTANGULAR SAFE OPERATING AREA
- WIDE ACCIDENTAL OVERLOAD AREA


## APPLICATIONS

- UNINTERRUPTABLE POWER SUPPLY
- SWITCH MODE POWER SUPPLIES
- MOTOR CONTROL


## DESCRIPTION

The BUT92 is a Multiepitaxial Planar NPN Transistor in TO-3 package. It is intended for use in high frequency and efficency converters, switching regulators and motor control.


## INTERNAL SCHEMATIC DIAGRAM




TO-3
(version "S")

## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CEV}}$ | Collector-Emitter Voltage $\left(\mathrm{V}_{\mathrm{BE}}=-1.5 \mathrm{~V}\right)$ | 350 | V |
| $\mathrm{~V}_{\text {CEO }}$ | Collector-Emitter Voltage $\left(\mathrm{I}_{\mathrm{B}}=0\right)$ | 250 | V |
| $\mathrm{~V}_{\text {EBO }}$ | Emitter-Base Voltage $\left(\mathrm{I}_{\mathrm{C}}=0\right)$ | 7 | V |
| $\mathrm{I}_{\mathrm{E}}$ | Emitter Current | 50 | A |
| $\mathrm{I}_{\mathrm{EM}}$ | Emitter Peak Current $\left(\mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}\right)$ | 75 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base Current | 10 | A |
| $\mathrm{I}_{\mathrm{BM}}$ | Base Peak Current $\quad\left(\mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}\right)$ | 15 | A |
| $\mathrm{P}_{\text {tot }}$ | Total Power Dissipation at $\mathrm{T}_{\text {case }} \leq 25^{\circ} \mathrm{C}$ | 250 | W |
| $\mathrm{~T}_{\text {stg }}$ | Storage Temperature | -65 to 200 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | Junction Temperature | 200 | ${ }^{\circ} \mathrm{C}$ |

## THERMAL DATA

| $R_{\text {thj-case }}$ | Thermal Resistance Junction-case | Max | 0.7 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| :--- | :--- | :--- | :--- | :--- |

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\text {case }}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ICER | Collector Cut-off Current ( $\mathrm{R}_{\mathrm{BE}}=10 \Omega$ ) | $\begin{array}{ll} V_{C E}=V_{C E V} & \\ V_{C E}=V_{C E V} & T_{C}=10{ }^{\circ} \mathrm{C} \end{array}$ |  |  | $\begin{gathered} 0.4 \\ 4 \end{gathered}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \end{aligned}$ |
| ICEV | Collector Cut-off Current ( V BE $=-1.5 \mathrm{~V}$ ) | $\begin{array}{ll} \mathrm{V}_{\mathrm{CE}}=\mathrm{V}_{\mathrm{CEV}} & \\ \mathrm{~V}_{\mathrm{CE}}=\mathrm{V}_{\mathrm{CEV}} & \mathrm{~T}_{\mathrm{C}}=10{ }^{\circ} \mathrm{C} \end{array}$ |  |  | $\begin{gathered} 0.2 \\ 2 \end{gathered}$ | $\begin{gathered} \mathrm{mA} \\ \mathrm{~mA} \end{gathered}$ |
| Iebo | Emitter Cut-off Current ( $\mathrm{I}_{\mathrm{C}}=0$ ) | $\mathrm{V}_{\mathrm{EB}}=7 \mathrm{~V}$ |  |  | 1 | mA |
| $\mathrm{V}_{\text {CEO(sus)* }}$ | Collector-Emitter Sustaining Voltage $\left(I_{B}=0\right)$ | $\mathrm{IC}=0.2 \mathrm{~A} \quad \mathrm{~L}=25 \mathrm{mH}$ | 250 |  |  | V |
| $V_{\text {Ebo }}$ | Emitter-Base Voltage $\left(I_{C}=0\right)$ | $\mathrm{I}_{\mathrm{E}}=50 \mathrm{~mA}$ | 7 |  |  | V |
| $\mathrm{V}_{\mathrm{CE} \text { (sat) }}{ }^{*}$ | Collector-Emitter Saturation Voltage | $\begin{array}{lll} \mathrm{I}_{\mathrm{C}}=35 \mathrm{~A} & \mathrm{I}_{\mathrm{B}}=3.5 \mathrm{~A} & \\ \mathrm{I}_{\mathrm{C}}=35 \mathrm{~A} & \mathrm{I}_{\mathrm{B}}=3.5 \mathrm{~A} & \mathrm{~T}_{\mathrm{C}}=100^{\circ} \mathrm{C} \end{array}$ |  | $\begin{gathered} 0.8 \\ 1.25 \end{gathered}$ | $\begin{aligned} & 1.2 \\ & 1.9 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\mathrm{BE} \text { (sat)* }}$ | Base-Emitter Saturation Voltage | $\begin{array}{lll} \mathrm{I}_{\mathrm{C}}=35 \mathrm{~A} & \mathrm{I}_{\mathrm{B}}=3.5 \mathrm{~A} & \\ \mathrm{I}_{\mathrm{C}}=35 \mathrm{~A} & \mathrm{I}_{\mathrm{B}}=3.5 \mathrm{~A} & \mathrm{~T}_{\mathrm{C}}=10{ }^{\circ} \mathrm{C} \end{array}$ |  | $\begin{aligned} & 1.2 \\ & 1.2 \end{aligned}$ | $\begin{aligned} & 1.5 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| dic/dt | Rated of Rise on-state Collector Current | $\begin{array}{ll} \mathrm{V}_{\mathrm{CC}}=200 \mathrm{~V} & \mathrm{I}_{\mathrm{B} 1}=5.25 \mathrm{~A} \quad \mathrm{R}_{\mathrm{C}}=0 \\ \mathrm{t}_{\mathrm{p}}=3 \mu \mathrm{~S} & \mathrm{~T}_{\mathrm{C}}=100^{\circ} \mathrm{C} \end{array}$ | 125 | 200 |  | A/ $\mu \mathrm{s}$ |
| $\mathrm{V}_{\mathrm{CE}(3 \mu \mathrm{~s})}$ * | Collector-Emitter Dynamic Voltage | $\begin{array}{\|ll} \hline \mathrm{V}_{\mathrm{CC}}=200 \mathrm{~V} & \mathrm{I}_{\mathrm{B} 1}=5.25 \mathrm{~A} \\ \mathrm{R}_{\mathrm{C}}=5.7 \Omega & \mathrm{~T}_{\mathrm{C}}=100^{\circ} \mathrm{C} \\ \hline \end{array}$ |  | 3 | 6 | V |
| $\mathrm{V}_{\mathrm{CE} \text { (5 } \mu \mathrm{s} \text { )* }}$ | Collector-Emitter Dynamic Voltage | $\begin{array}{ll} \mathrm{V}_{\mathrm{CC}}=200 \mathrm{~V} & \mathrm{I}_{\mathrm{B} 1}=5.25 \mathrm{~A} \\ \mathrm{R}_{\mathrm{C}}=5.7 \Omega & \mathrm{~T}_{\mathrm{C}}=100^{\circ} \mathrm{C} \end{array}$ |  | 1.8 | 3 | V |

INDUCTIVE LOAD

| Symbol | Parameter | Test Conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \mathrm{t}_{\mathrm{s}} \\ & \mathrm{t}_{\mathrm{f}} \\ & \mathrm{t}_{\mathrm{c}} \end{aligned}$ | Storage Time Fall Time Crossover Time | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=200 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{C}}=35 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{BB}}=-5 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{B} 2}=0.7 \Omega \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\text {Clamp }}=250 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{B} 1}=3.5 \mathrm{~A} \\ & \mathrm{~L}_{\mathrm{C}}=0.28 \mathrm{mH} \\ & \mathrm{~T}_{\mathrm{C}}=100{ }^{\circ} \mathrm{C} \end{aligned}$ |  | $\begin{gathered} 1.4 \\ 0.15 \\ 0.3 \end{gathered}$ | $\begin{gathered} 3 \\ 0.4 \\ 0.7 \end{gathered}$ | $\begin{aligned} & \mu \mathrm{s} \\ & \mu \mathrm{~s} \\ & \mu \mathrm{~s} \end{aligned}$ |
| $V_{\text {cew }}$ | Maximum Collector Emitter Voltage without Snubber | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=50 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{BB}}=-5 \mathrm{~V} \\ & \mathrm{~L}_{\mathrm{C}}=48 \mu \mathrm{H} \\ & \mathrm{~T}_{\mathrm{C}}=125^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{cWoff}}=52 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{B} 1}=3.5 \mathrm{~A} \\ & \mathrm{R}_{\mathrm{B} 2}=0.7 \Omega \end{aligned}$ | 250 |  |  | V |

[^0]
## TO-3 (version S) MECHANICAL DATA

| DIM. | mm |  |  |  | inch |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 11.00 |  | 13.10 | 0.433 |  | 0.516 |
| B | 1.47 |  | 1.60 | 0.058 |  | 0.063 |
| C | 1.50 |  | 1.65 | 0.059 |  | 0.065 |
| D | 8.32 |  | 8.92 | 0.327 |  | 0.351 |
| E | 19.00 |  | 20.00 | 0.748 |  | 0.787 |
| G | 10.70 |  | 11.10 | 0.421 |  | 0.437 |
| N | 16.50 |  | 17.20 | 0.649 |  | 0.677 |
| P | 25.00 |  | 26.00 | 0.984 |  | 1.023 |
| U | 4.00 |  | 4.09 | 0.157 |  | 0.161 |
| V | 30.50 |  | 39.30 | 1.515 |  | 1.547 |



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[^0]:    * Pulsed : Pulse duration = $300 \mu \mathrm{~s}$, duty cycle = $2 \%$

